

Description

The SiT9347 is a 220.00001 MHz to 725 MHz differential MEMS XO engineered for low-jitter, high reliability applications. Utilizing SiTime's unique DualMEMS® temperature sensing and TurboCompensation® technology, the SiT9347 delivers exceptional dynamic performance by providing resistance to airflow, thermal gradients, shock and vibration. This device also integrates multiple on-chip regulators to filter power supply noise, eliminating the need for a dedicated external LDO.

The SiT9347 can be factory programmed for any combination of frequency, stability, voltage, and output signaling. Programmability enables designers to optimize clock configurations while eliminating long lead times and customization costs associated with quartz devices where each frequency is custom built.

The wide frequency range and programmability makes this device ideal for aerospace, industrial and defense applications that require a variety of frequencies and operate in noisy environments.

Refer to Manufacturing Notes for proper reflow profile, tape and reel dimension, and other manufacturing related information.

Features

- 0.1 ppb/g acceleration sensitivity for harsh environments
- Any frequency between 220.000001 MHz and 725 MHz, accurate to 6 decimal places.
 - For HCSL output signaling, maximum frequency is 500 MHz. Contact SiTime for higher frequency options. (For additional frequencies, refer to SiT9346 datasheets)
- LVPECL, Low-swing LVPECL, LVDS and HCSL output signaling
- 0.1 ps RMS phase jitter (random) for Ethernet applications
- Frequency stability as low ±10 ppm
- Wide temperature range from -40°C to 105°C
 Contact SiTime for higher temperature range options
- Industry-standard packages: 3.2 x 2.5 mm², 7.0 x 5.0 mm² and 5.0 x 3.2 mm² package

Applications

- Airborne Communications
- Command and Control
- Field Communications
- Airframe/Engine Management Control
- Radar
- SATCOM



Block Diagram

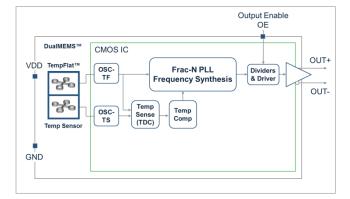


Figure 1. SiT9347 Block Diagram

Package Pinout

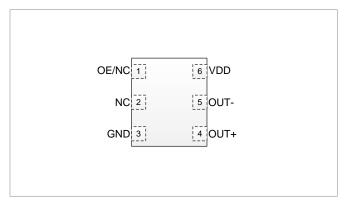
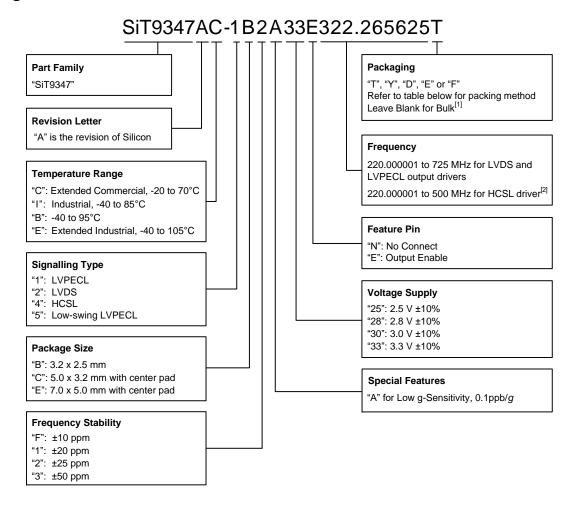


Figure 2. Pin Assignments (Top view) (Refer to Table 6 for Pin Descriptions)



Ordering Information



- 1. Bulk is available for sampling only, (up to 24 u).
- 2. Contact SiTime for higher frequency HCSL options.

Table 1. Ordering Codes for Supported Tape & Reel Packing Method

| Device Size (mm x mm) | 8 mm T&R (3ku) | 8 mm T&R (1ku) | 12 mm T&R (3ku) | 12 mm T&R (1ku) | 12 mm T&R (<250pcs) | 16 mm T&R (3ku) | 16 mm T&R (1ku) |
|--------------------------|-------------------|-------------------|--------------------|--------------------|------------------------|--------------------|--------------------|
| 7.0 x 5.0 | _ | | | | | Т | Υ |
| 5.0 x 3.2 | _ | | Т | Υ | F | | _ |
| 3.2 x 2.5 | D | E | | | 1 | | _ |



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Electrical Characteristics

All Min and Max limits in the Electrical Characteristics tables are specified over temperature and rated operating voltage with standard output termination shown in the termination diagrams. Typical values are at 25°C at nominal supply voltage.

Table 2. Electrical Characteristics - Common to LVPECL, Low-swing LVPECL, LVDS and HCSL

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Condition |
|---|---------|------------|------|-----------|-------------|---|
| | | | F | requency | Range | |
| Output Frequency Range | f | 220.000001 | - | 725 | MHz | Accurate to 6 decimal places |
| | | | Fr | equency | Stability | |
| Frequency Stability | F_stab | -10 | - | +10 | ppm | Inclusive of initial tolerance, operating temperature, rated power |
| | | -20 | - | +20 | ppm | supply voltage and load variations |
| | | -25 | _ | +25 | ppm | |
| | | -50 | - | +50 | ppm | |
| First Year Aging | F_1y | -0.7 | ±0.4 | +0.7 | ppm | At 85°C |
| 5 Year Aging | F_5y | -1.1 | ±0.7 | +1.1 | ppm | At 85°C |
| 10 Year Aging | F_10y | -1.3 | ±0.8 | +1.3 | ppm | At 85°C |
| 20 Year Aging | F_20y | -1.5 | ±1.0 | +1.5 | ppm | At 85°C |
| | | | Te | emperatur | e Range | |
| Operating Temperature Range | T_use | -20 | - | +70 | °C | Extended Commercial |
| | | -40 | - | +85 | °C | Industrial |
| | | -40 | ı | +95 | °C | |
| | | -40 | - | +105 | °C | Extended Industrial |
| | | | Rug | ged Chara | acteristics | |
| Acceleration (g) sensitivity, Gamma Vector | F_g | - | - | 0.1 | ppb/g | Low sensitivity grade; total gamma over 3 axes; 15 Hz to 2 kHz; MIL-PRF-55310, computed per section 4.8.18.3.1 |
| | | | | Supply Vo | oltage | |
| Supply Voltage | Vdd | 2.97 | 3.30 | 3.63 | V | |
| | | 2.70 | 3.00 | 3.30 | V | |
| | | 2.52 | 2.80 | 3.08 | V | |
| | | 2.25 | 2.50 | 2.75 | V | |
| | | | Inp | ut Charac | teristics | |
| Input Voltage High | VIH | 70% | 1 | _ | Vdd | Pin 1, OE |
| Input Voltage Low | VIL | - | ı | 30% | Vdd | Pin 1, OE |
| Input Pull-up Impedance | Z_in | - | 100 | - | kΩ | Pin 1, OE logic high or logic low |
| | | | Out | put Chara | cteristics | |
| Duty Cycle | DC | 45 | - | 55 | % | |
| | | | Star | tup and C | E Timing | |
| Startup Time | T_start | - | - | 3.0 | ms | Measured from the time Vdd reaches its rated minimum value. |
| OE Enable/Disable Time | T_oe | _ | - | 3.8 | μs | f = 322.265625 MHz. Measured from the time OE pin reaches rated VIH and VIL to the time clock pins reach 90% of swing and high-Z. See Figure 8 and Figure 9 |



Table 3. Electrical Characteristics – LVPECL Specific

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Condition |
|-----------------------------------|----------|----------|---------------|--------------|----------|--|
| | | | | rent Consu | mption | |
| Current Consumption | ldd | - | - | 94 | mA | Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V |
| OE Disable Supply Current | I_OE | - | - | 63 | mA | OE = Low |
| Output Disable Leakage Current | l_leak | - | 0.15 | - | μΑ | OE = Low |
| Maximum Output Current | I_driver | - | - | 33 | mA | Maximum average current drawn from OUT+ or OUT- |
| | • | | Output Ch | aracteristic | s for LV | PECL |
| Output High Voltage | VOH | Vdd-1.15 | - | Vdd-0.7 | V | See Figure 4 |
| Output Low Voltage | VOL | Vdd-2.0 | ı | Vdd-1.5 | ٧ | See Figure 4 |
| Output Differential Voltage Swing | V_Swing | 1.2 | 1.6 | 2.0 | V | See Figure 5 |
| Rise/Fall Time | Tr, Tf | _ | 225 | 330 | ps | 20% to 80%, see Figure 5 |
| | | Outp | ut Charact | eristics for | Low-sw | ing LVPECL |
| Output High Voltage | VOH | Vdd-1.2 | - | Vdd-0.75 | ٧ | See Figure 4 |
| Output Low Voltage | VOL | Vdd-1.8 | - | Vdd-1.25 | V | See Figure 4 |
| Output Differential Voltage | V_Swing | 0.4 | 1 | 1.2 | V | Output frequency 1 to 220 MHz, See Figure 5 |
| Swing | | 0.4 | 1 | 1.6 | V | Output frequency greater than 220 MHz, See Figure 5 |
| Rise/Fall Time | Tr, Tf | _ | 225 | 320 | ps | 20% to 80%. See Figure 5 |
| | | | Jitter – | 7.0 x 5.0 m | m Packa | nge . |
| RMS Period Jitter[3] | T_jitt | - | 1.0 | 1.6 | Ps | f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V |
| RMS Phase Jitter (random) | T_phj | | 0.220 | 0.270 | Ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70° C and -40 to 85° C |
| | | _ | 0.220 | 0.300 | Ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -40 to 95°C and -40 to 105°C |
| | | _ | 0.1 | - | Ps | f = 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, Includes spurs, all Vdd levels |
| | • | Jitte | er – 5.0 x 3. | 2 and 3.2 x | 2.5 mm | Packages |
| RMS Period Jitter[3] | T_jitt | _ | 1.0 | 1.6 | Ps | f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V |
| RMS Phase Jitter (random) | T_phj | - | 0.225 | 0.282 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40 to 85°C. |
| | | _ | 0.225 | 0.315 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -40 to 95°C and -40 to 105°C |
| | | _ | 0.1 | _ | ps | f = 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, Includes spurs, all Vdd levels |

Notes:
3. Measured according to JESD65B.



Table 4. Electrical Characteristics – LVDS Specific

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Condition | |
|----------------------------------|--------|-------|--------------|-------------|----------|---|--|
| | | | Cu | rrent Cons | sumption | | |
| Current Consumption | ldd | - | - | 85 | mA | Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V | |
| OE Disable Supply Current | I_OE | - | - | 63 | mA | OE = Low | |
| Output Disable Leakage Current | l_leak | _ | 0.15 | - | μΑ | OE = Low | |
| Output Characteristics | | | | | | | |
| Differential Output Voltage | VOD | 300 | _ | 450 | mV | See Figure 6 | |
| VOD Magnitude Change | ΔVOD | _ | - | 50 | mV | See Figure 6 | |
| Offset Voltage | VOS | 1.125 | - | 1.375 | V | See Figure 6 | |
| VOS Magnitude Change | ΔVOS | _ | - | 50 | mV | See Figure 6 | |
| Rise/Fall Time | Tr, Tf | _ | 370 | 470 | ps | Measured with 2 pF capacitive loading to GND, 20% to 80%, see Figure 3 | |
| | | | Jitter - | - 7.0 x 5.0 | mm Packa | nge | |
| RMS Period Jitter ^[4] | T_jitt | _ | 0.92 | 1.6 | ps | f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V | |
| RMS Phase Jitter (random) | T_phj | - | 0.215 | 0.265 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40-85°C | |
| | | - | 0.215 | 0.280 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges are -40 to 95°C and -40 to 105°C | |
| | | - | 0.1 | - | ps | f = 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz. Includes spurs for all Vdd levels. | |
| | | Jitt | er – 5.0 x 3 | 3.2 and 3.2 | x 2.5 mm | Packages | |
| RMS Period Jitter ^[4] | T_jitt | - | 0.92 | 1.6 | ps | f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V | |
| RMS Phase Jitter (random) | T_phj | - | 0.235 | 0.282 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40-85°C | |
| | | _ | 0.235 | 0.310 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges are -40 to 95°C and -40 to 105°C | |
| | | _ | 0.1 | ı | ps | f = 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz. Includes spurs for all Vdd levels. | |

Notes:

4. Measured according to JESD65B.



Table 5. Electrical Characteristics - HCSL Specific

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Condition |
|-----------------------------------|----------|-------|--------------|-------------|------------|---|
| | | | Cu | rrent Cons | sumption | |
| Current Consumption | Idd | _ | _ | 97 | mA | Excluding Load Termination Current, Vdd = 3.3 V or 2.5 V |
| OE Disable Supply Current | I_OE | _ | - | 63 | mA | OE = Low |
| Output Disable Leakage Current | I_leak | _ | 0.15 | - | μА | OE = Low |
| Maximum Output Current | I_driver | - | - | 35 | mA | Maximum average current drawn from OUT+ or OUT- |
| | | | Out | tput Chara | cteristics | |
| Output High Voltage | VOH | 0.60 | - | 0.90 | V | See Figure 4 |
| Output Low Voltage | VOL | -0.05 | - | 0.08 | V | See Figure 4 |
| Output Differential Voltage Swing | V_Swing | 1.2 | 1.4 | 1.9 | V | See Figure 5 |
| Rise/Fall Time | Tr, Tf | ı | 360 | 505 | ps | Measured with 2 pF capacitive loading to GND, 20% to 80%, see Figure 4 |
| | | | Jitter - | - 7.0 x 5.0 | mm Packa | ge |
| RMS Period Jitter ^[5] | T_jitt | ı | 1.0 | 1.6 | ps | f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V |
| RMS Phase Jitter (random) | T_phj | - | 0.215 | 0.265 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40 to 85°C |
| | | - | 0.215 | 0.282 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature range ranges -40 to 95°C and -40 to 105°C |
| | | - | 0.1 | - | ps | f = 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, Includes spurs, all Vdd levels |
| | | Jitt | er – 5.0 x 3 | 3.2 and 3.2 | x 2.5 mm | Packages |
| RMS Period Jitter ^[5] | T_jitt | _ | 1.0 | 1.6 | ps | f = 100, 156.25 or 212.5 MHz, Vdd = 3.3 V or 2.5 V |
| RMS Phase Jitter (random) | T_phj | ı | 0.235 | 0.282 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -20 to 70°C and -40 to 85°C |
| | | - | 0.235 | 0.305 | ps | f = 322.265625 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdd levels, includes spurs. Temperature ranges -40 to 95°C and -40 to 105°C |
| | | ı | 0.1 | ı | ps | f = 322.265625 MHz, IEEE802.3-2005 10GbE jitter mask integration bandwidth = 1.875 MHz to 20 MHz, Includes spurs for all Vdd levels. |

Note:

Measured according to JESD65B.

Table 6. Pin Description

| Pin | Мар | | Functionality |
|-----|--------------------------|-----------------------|--|
| | 05/5/0 | Output Enable (OE) | H ^[6] : specified frequency output L: output is high impedance |
| 1 | 1 OE/NC Non Connect (NC) | | H or L or Open: No effect on output frequency or other device functions. |
| 2 | NC | NA | No Connect; Leave it floating or connect to GND for better heat dissipation |
| 3 | GND | Power | VDD Power Supply Ground |
| 4 | OUT+ | Output | Oscillator output |
| 5 | OUT- | Output | Complementary oscillator output |
| 6 | VDD | Power | Power supply voltage ^[7] |

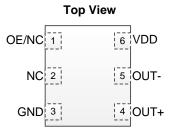


Figure 3. Pin Assignments

- 6. In OE mode, a pull-up resistor of 10 k Ω or less is recommended if pin 1 is not externally driven.
- 7. A capacitor of value 0.1 μF or higher between VDD and GND is required. An additional 10 μF capacitor between VDD and GND is required for the best phase jitter performance.



Table 7. Absolute Maximum Ratings

Caution: Attempted operation outside the absolute maximum ratings may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

| Parameter | Min. | Max. | Unit |
|--|------|------------|------|
| Vdd | -0.5 | 4.0 | V |
| VIH | | Vdd + 0.3V | V |
| VIL | -0.3 | | V |
| Storage Temperature | -65 | 150 | °C |
| Maximum Junction Temperature | | 130 | °C |
| Soldering Temperature (follow standard Pb-free soldering guidelines) | | 260 | °C |

Table 8. Thermal Considerations[8]

| Package | θ _{JA} , 4 Layer Board (°C/W) | θ _{JC} , Bottom (°C/W) |
|-------------|--|---------------------------------|
| 3225, 6-pin | 80 | 30 |
| 5032, 6-pin | 53 | 20 |
| 7050, 6-pin | 52 | 19 |

Notes:

8. Refer to JESD51 for θ_{JA} and θ_{JC} definitions, and reference layout used to determine the θ_{JA} and θ_{JC} values in the above table.

Table 9. Maximum Operating Junction Temperature[9]

| Max Operating Temperature (ambient) | Maximum Operating Junction Temperature |
|-------------------------------------|--|
| 70°C | 95°C |
| 85°C | 110°C |
| 95°C | 120°C |
| 105°C | 130°C |

Notes:

9. Datasheet specifications are not guaranteed if junction temperature exceeds the maximum operating junction temperature.

Table 10. Environmental Compliance

| Parameter | Test Conditions | Value | Unit |
|--|---------------------------|-----------|------|
| Mechanical Shock Resistance | MIL-STD-883F, Method 2002 | 10,000 | g |
| Mechanical Vibration Resistance | MIL-STD-883F, Method 2007 | 70 | g |
| Soldering Temperature (follow standard Pb free soldering guidelines) | MIL-STD-883F, Method 2003 | 260 | °C |
| Moisture Sensitivity Level | MSL1 @ 260°C | | |
| Electrostatic Discharge (HBM) | HBM, JESD22-A114 | 2,000 | V |
| Charge-Device Model ESD Protection | JESD220C101 | 750 | V |
| Latch-up Tolerance | JESD78 | Compliant | |



Waveform Diagrams

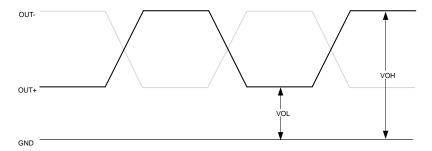


Figure 4. LVPECL, Low-swing LVPECL, and HCSL Voltage Levels per Differential Pin (i.e. OUT+, or OUT-)

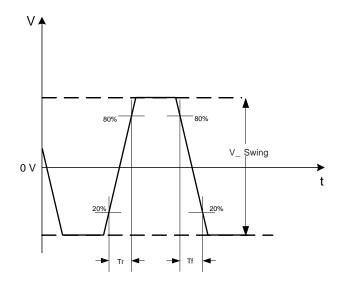


Figure 5. LVPECL, Low-swing LVPECL, and HCSL Voltage Levels Across Differential Pair (i.e. OUT+ minus OUT-)



Waveform Diagrams (continued)

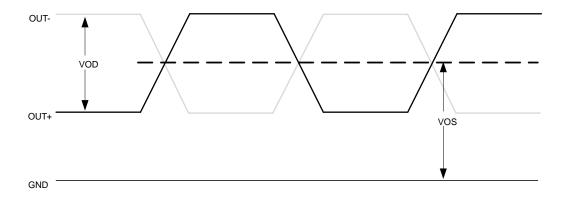


Figure 6. LVDS Voltage Levels per Differential Pin (i.e. OUT+, or OUT-)

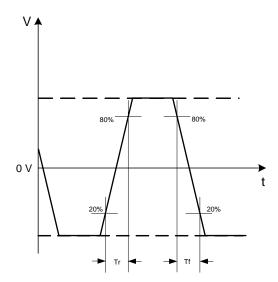


Figure 7. LVDS Differential Waveform (i.e. OUT+ minus OUT-)

Timing Diagrams

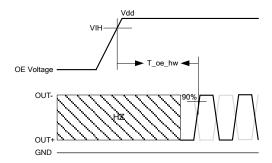


Figure 8. Hardware OE Enable Timing

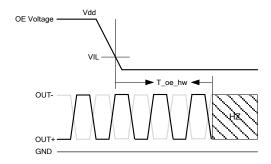


Figure 9. Hardware OE Disable Timing



Termination Diagrams

LVPECL and Low-swing LVPECL

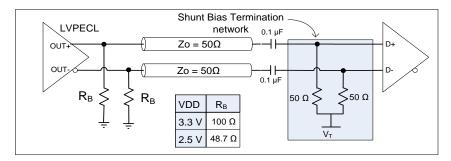


Figure 10. LVPECL and Low-swing LVPECL with AC-coupled Termination

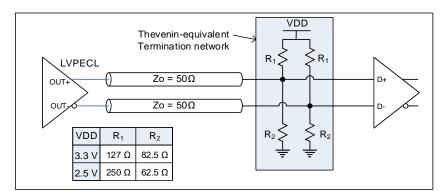


Figure 11. LVPECL and Low-swing LVPECL DC-coupled Load Termination with Thevenin Equivalent Network

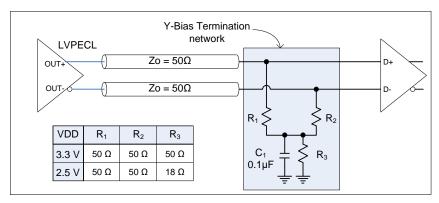


Figure 12. LVPECL and Low-swing LVPECL with Y-Bias Termination

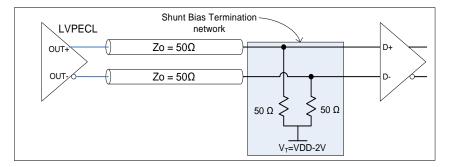


Figure 13. LVPECL and Low-swing LVPECL with DC-coupled Parallel Shunt Load Termination



Termination Diagrams (continued)

LVDS

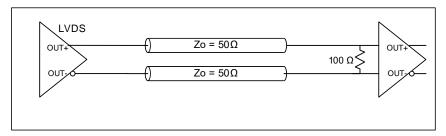


Figure 14. LVDS Single DC Termination at the Load

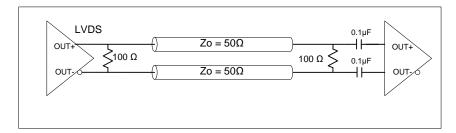


Figure 15. LVDS double AC Termination with Capacitor Close to the Load

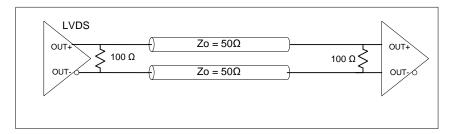


Figure 16. LVDS Double DC Termination

HCSL

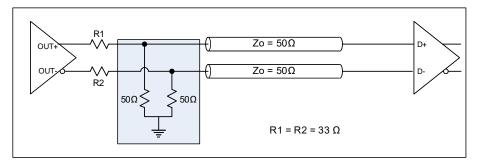
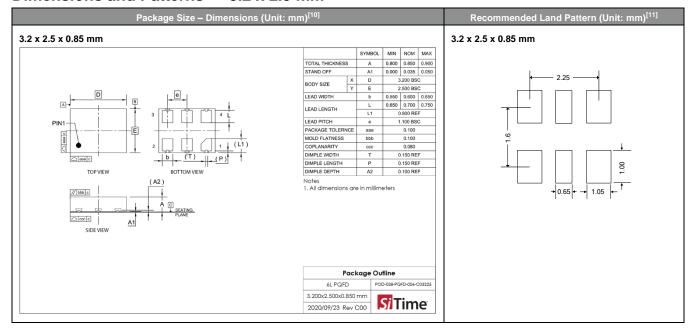


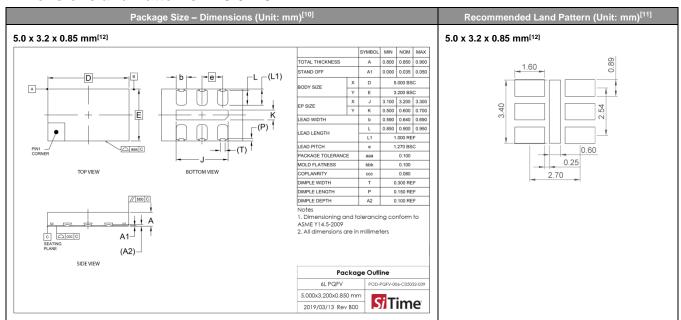
Figure 17. HCSL Interface Termination



Dimensions and Patterns — 3.2 x 2.5 mm²



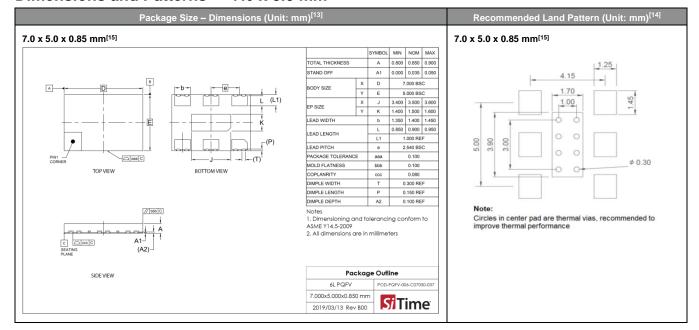
Dimensions and Patterns — 5.0 x 3.2 mm²



- 10. Top Marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
- 11. A capacitor of value 0.1 µF or higher between VDD and GND is required. An additional 10 µF capacitor between VDD and GND is required for the best phase jitter performance.
- 12. The center pad has no electrical function. Soldering down the center pad to the GND is recommended for best thermal dissipation, but is optional.



Dimensions and Patterns — 7.0 x 5.0 mm²



- 13. Top Marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
- 14. A capacitor of value 0.1 µF or higher between VDD and GND is required. An additional 10 µF capacitor between VDD and GND is required for the best phase jitter performance.
- 15. The center pad has no electrical function. Soldering down the center pad to the GND is recommended for best thermal dissipation, but is optional.



Additional Information

Table 11. Additional Information

| Document | Description | Download Link |
|---------------------------------------|--|--|
| ECCN #: EAR99 | Five character designation used on the commerce Control List (CCL) to identify dual use items for export control purposes. | |
| HTS Classification Code: 8542.39.0000 | A Harmonized Tariff Schedule (HTS) code developed by the World Customs Organization to classify/define internationally traded goods. | _ |
| Part number Generator | Tool used to create the part number based on desired features. | _ |
| Manufacturing Notes | Tape & Reel dimension, reflow profile and other manufacturing related info | https://www.sitime.com/sites/default/files/gated/Manufacturing-Notes-for-SiTime-Products.pdf |
| Qualification Reports | RoHS report, reliability reports, composition reports | http://www.sitime.com/support/quality-and-reliability |
| Performance Reports | Additional performance data such as phase noise, current consumption and jitter for selected frequencies | http://www.sitime.com/support/performance-measurement-report |
| Termination Techniques | Termination design recommendations | http://www.sitime.com/support/application-notes |
| Layout Techniques | Layout recommendations | http://www.sitime.com/support/application-notes |
| Evaluation Boards | SiT6085/6EB rev. 3.0, SiT6085EB rev.3.1 and SiT6097EB rev. 2.0 Evaluation Boards for Differential Oscillators User Manual | https://www.sitime.com/support/user-guides |



Revision History

Table 12. Revision History

| Revision | Release Date | Change Summary |
|----------|--------------|---|
| 0.5 | 22-Jul-2019 | Initial draft |
| 1.00 | 16-Feb-2021 | Updated package Dimensions Drawings Updated Table 8 Thermal Considerations for 5032 package Updated Table 2 specification for First Year Aging Added 5, 10, and 20 year aging specs Added Evaluation Boards SiT6085EB reference in Additional Information Rearranged layout, added Description, Block Diagram and TOC Tightened LVDS minimum VOD specification Added HTS code Added low-swing LVPECL package code and specifications Fixed Ordering typo, updated trademarks, date format, other formatting changes |
| 1.01 | 17-Mar-2021 | Updated L1 and Dimple Width package dimensions for 3.2 x 2.5 mm package |
| 1.02 | 21-Nov-2022 | Updated Ordering packaging information with F option Updated hyperlinks and icons on page 1. Disclaimer update |

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